

### Product Overview

The CMD307 is a highly efficient GaAs MMIC low noise amplifier ideally suited for EW and communications systems where small size and low power consumption are needed. At 12 GHz the device delivers greater than 19 dB of gain with a corresponding output 1 dB compression point of +11 dBm and noise figure of 1.8 dB. The CMD307 is a 50 ohm matched design which eliminates the need for external DC blocks and RF port matching. The CMD307 offers full passivation for increased reliability and moisture protection.

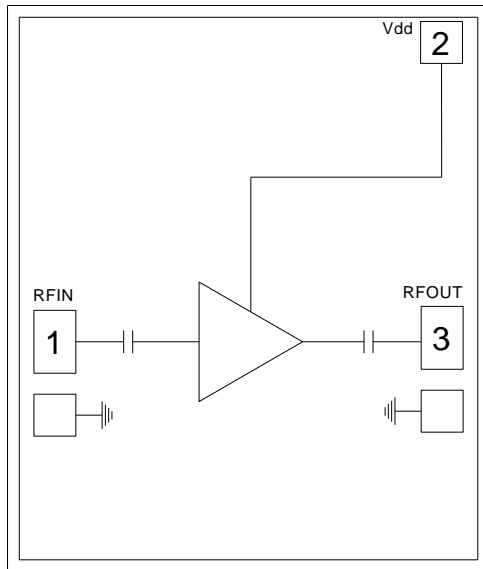
### Key Features

- Ultra Low Noise Performance
- Low Current Consumption
- Single Positive Supply Voltage
- Small Die Size

### Ordering Information

Part No.	Description
CMD307	100 pcs in gel pack

### Functional Block Diagram



### Electrical Performance ( $V_{dd} = 3.0\text{ V}$ , $T_A = 25^\circ\text{C}$ , $F = 12\text{ GHz}$ )

Parameter	Min	Typ	Max	Units
Frequency Range		8 - 16		GHz
Gain		19.5		dB
Noise Figure		1.8		dB
Input Return Loss		12		dB
Output Return Loss		16		dB
Output P1dB		12		dBm
Output IP3		25		dBm
Supply Current		51		mA

## Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, $V_{dd}$	5.0 V
RF Input Power	+ 20 dBm
Channel Temperature, $T_{ch}$	150° C
Power Dissipation, $P_{diss}$	338 mW
Thermal Resistance, $Q_{JC}$	192° C/W
Operating Temperature	-55 to 85° C
Storage Temperature	-55 to 150° C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

## Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
$V_{dd}$	2.0	3.0	4.0	V
$I_{dd}$		51		mA

Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

## Drain Current vs. Drain Voltage

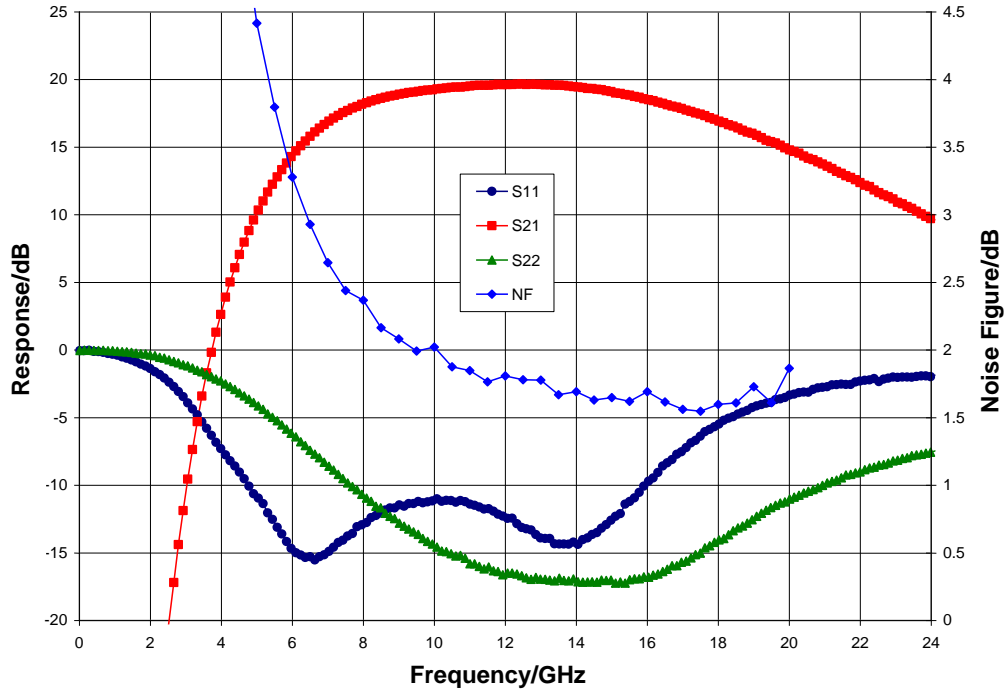
$V_{dd}$ (V)	$I_{dd}$ (mA)
2.0	47
3.0	51
4.0	55

## Electrical Specifications ( $V_{dd} = 3.0$ V, $T_A = 25^\circ$ C)

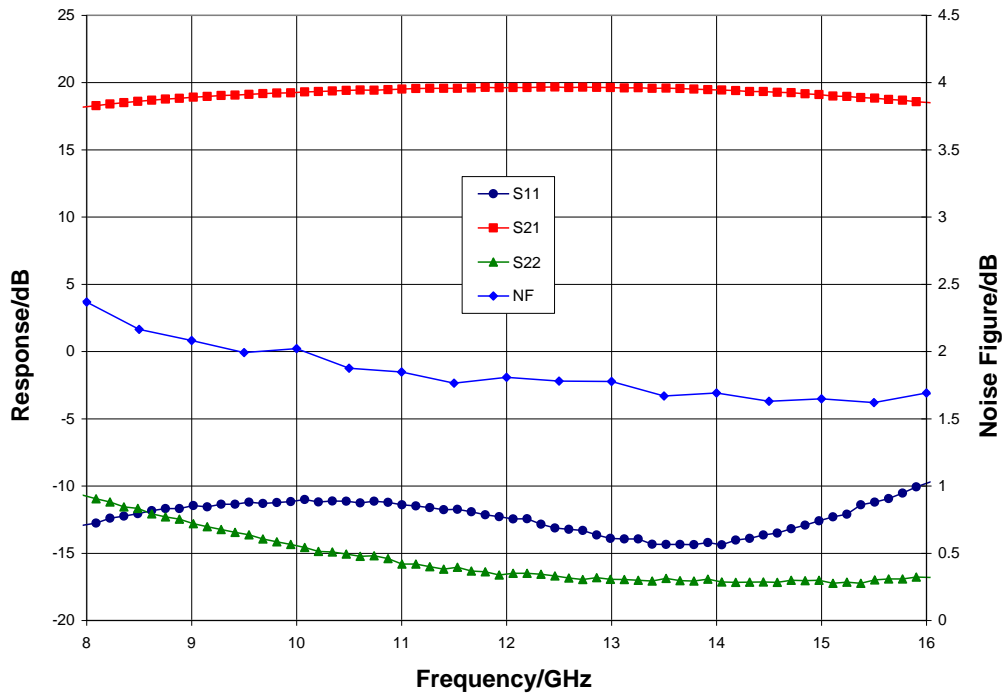
Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range	8 - 11			11 - 16			GHz
Gain	15	19		15.5	19.5		dB
Noise Figure		2	2.8		1.7	2.3	dB
Input Return Loss		11			13		dB
Output Return Loss		13			16		dB
Output P1dB		11			11.5		dBm
Output IP3		25			25		dBm
Supply Current	35	51	67	35	51	67	mA
Gain Temperature Coefficient		0.008			0.008		dB/°C
Noise Figure Temperature Coefficient		0.006			0.006		dB/°C

Typical Performance

Broadband Performance,  $V_{dd} = 3.0\text{ V}$ ,  $T_A = 25^\circ\text{C}$

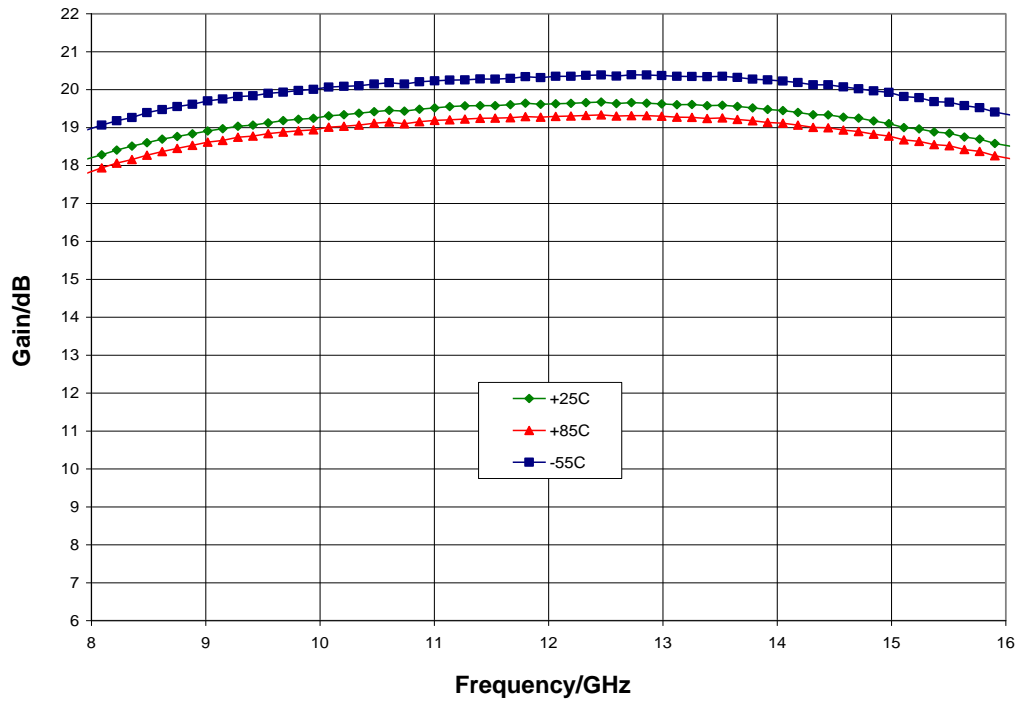


Narrow-band Performance,  $V_{dd} = 3.0\text{ V}$ ,  $T_A = 25^\circ\text{C}$

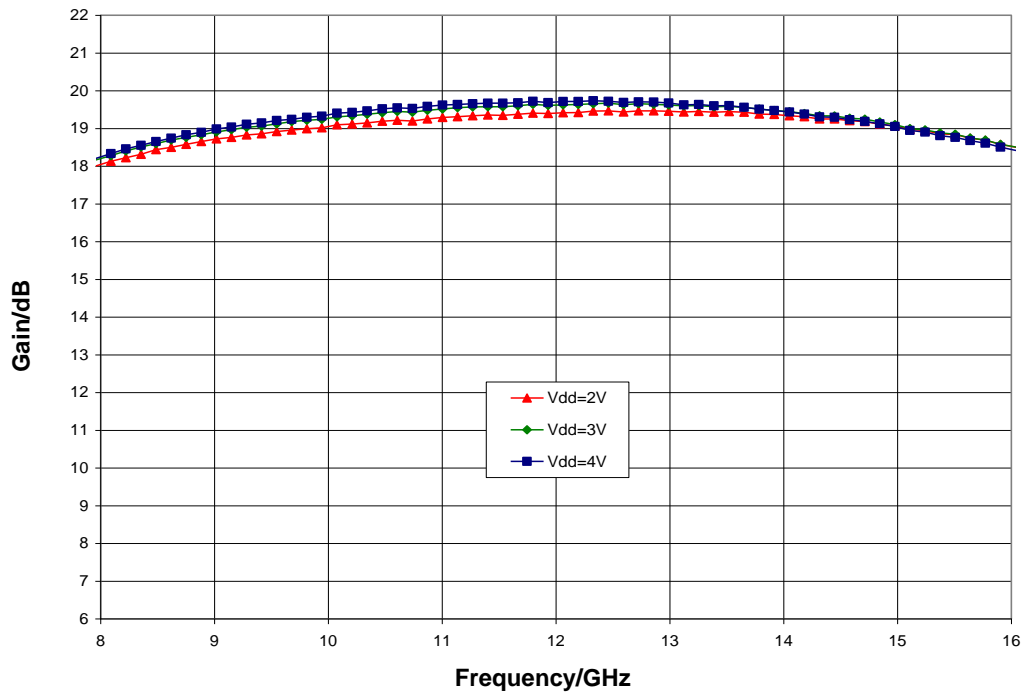


Typical Performance

Gain vs. Temperature,  $V_{dd} = 3.0\text{ V}$

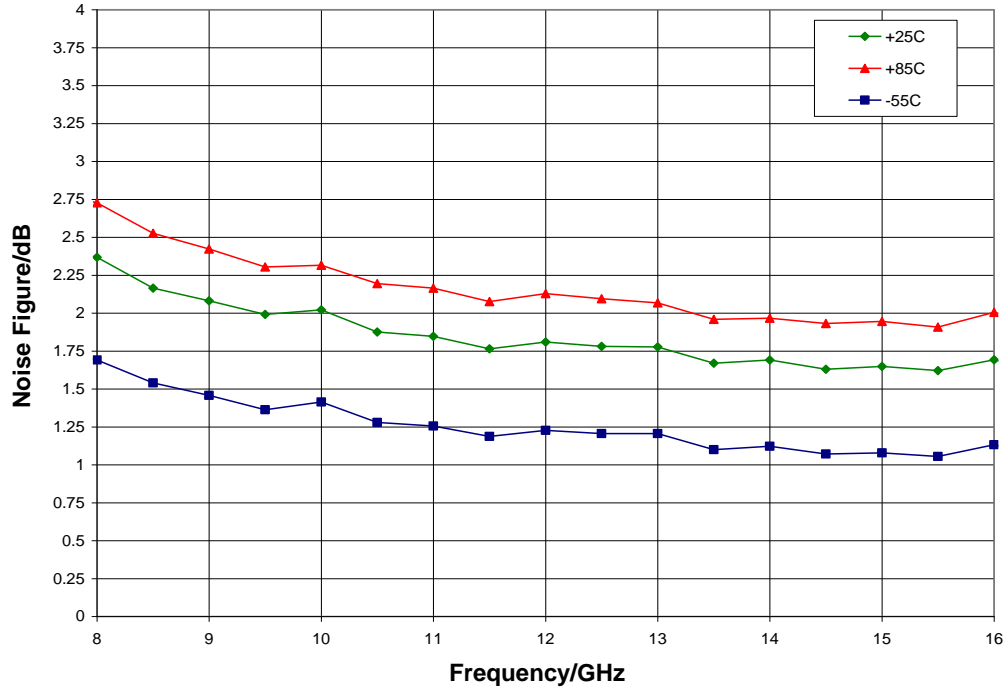


Gain vs.  $V_{dd}$ ,  $T_A = 25^\circ\text{ C}$

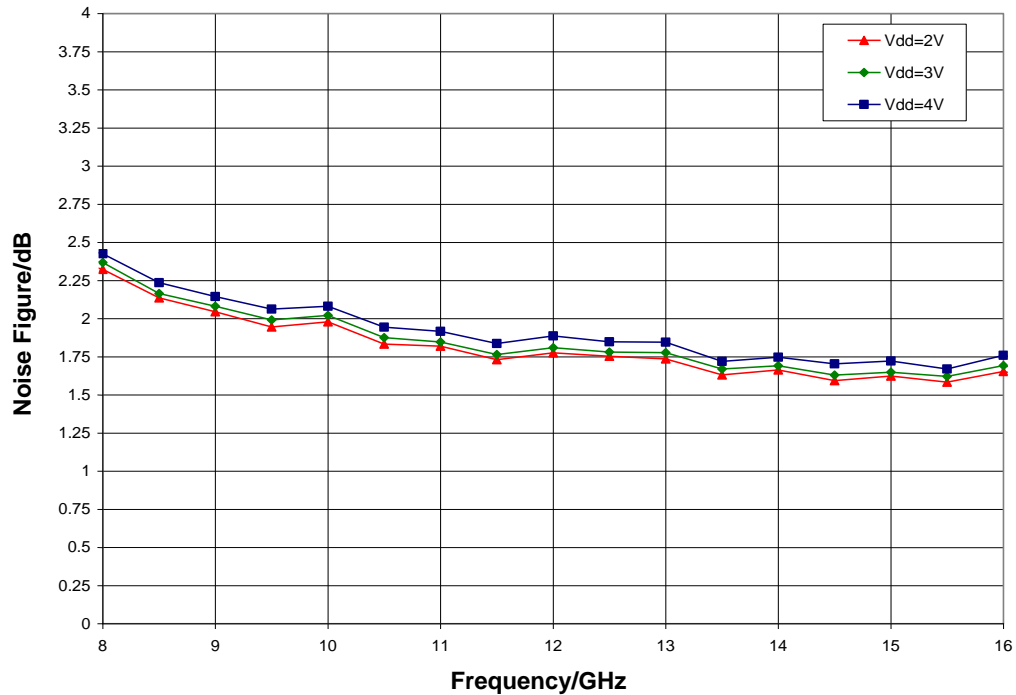


Typical Performance

Noise Figure vs. Temperature,  $V_{dd} = 3.0\text{ V}$

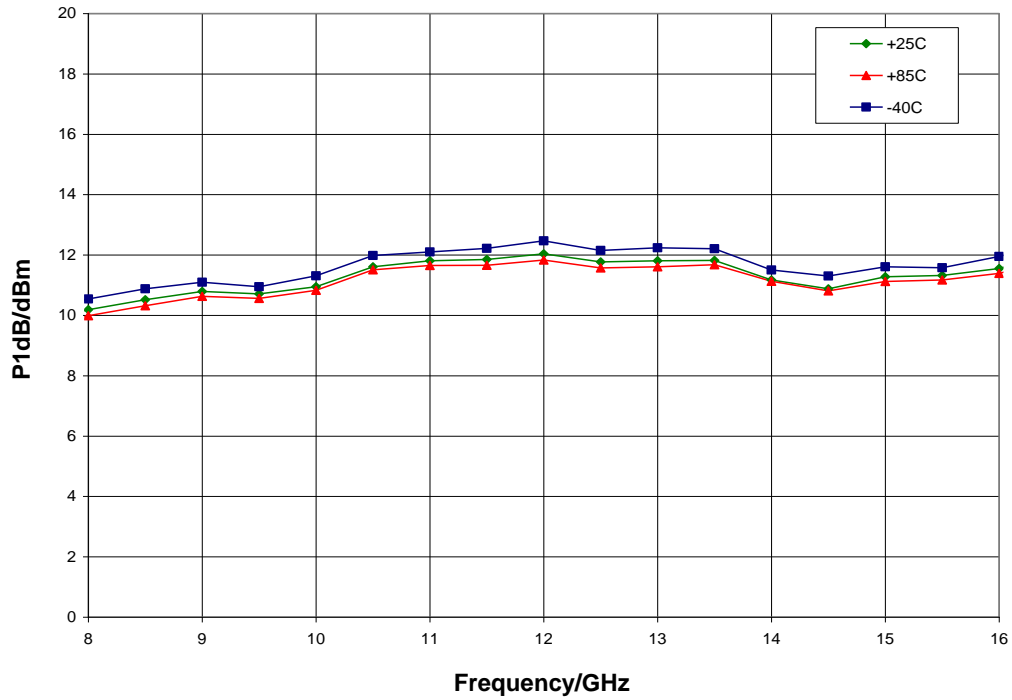


Noise Figure vs.  $V_{dd}$ ,  $T_A = 25^\circ\text{C}$

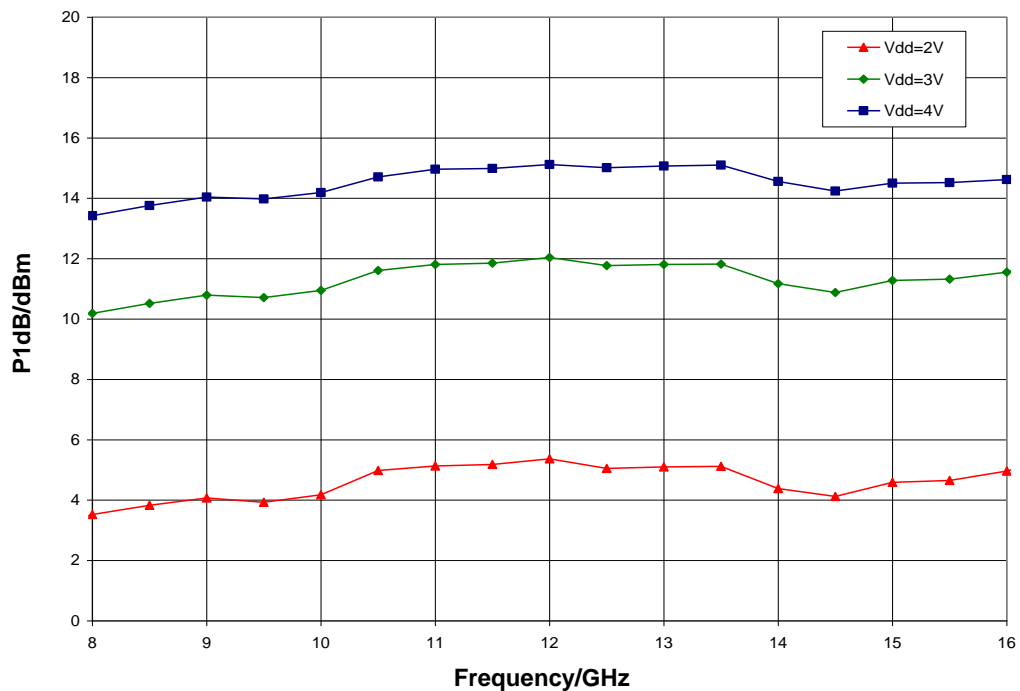


Typical Performance

P1dB vs. Temperature,  $V_{dd} = 3.0\text{ V}$

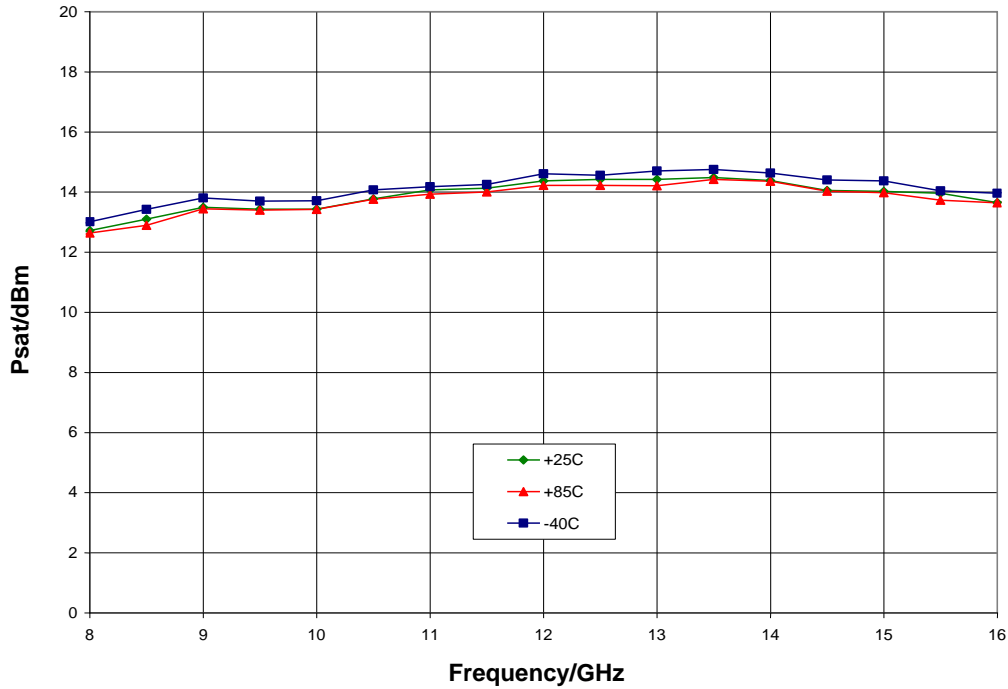


P1dB vs.  $V_{dd}$ ,  $T_A = 25^\circ\text{C}$

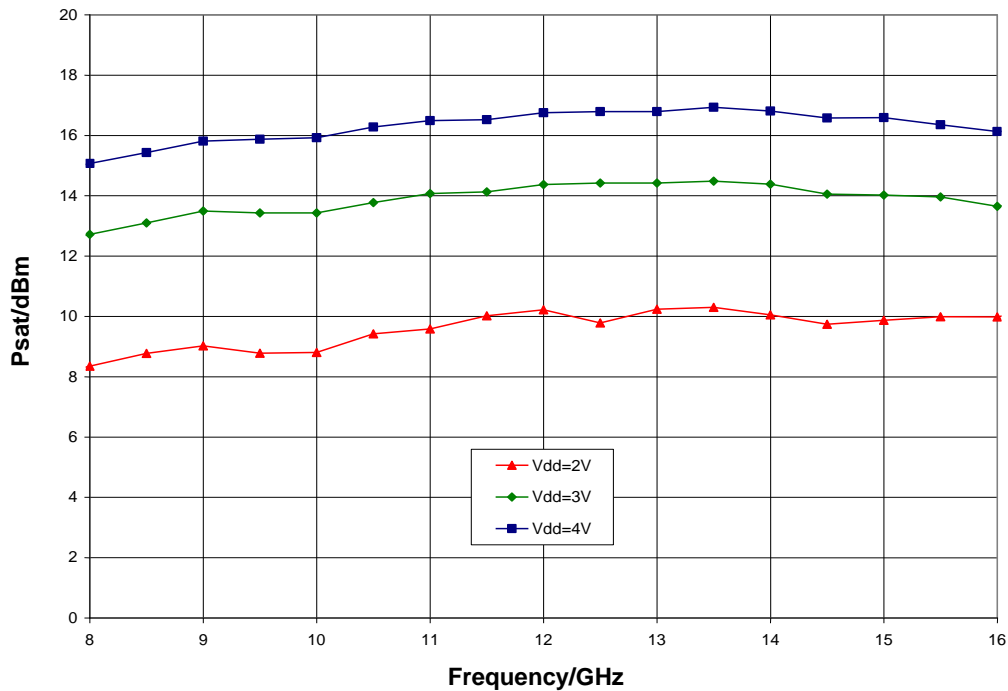


Typical Performance

Psat vs. Temperature,  $V_{dd} = 3.0\text{ V}$

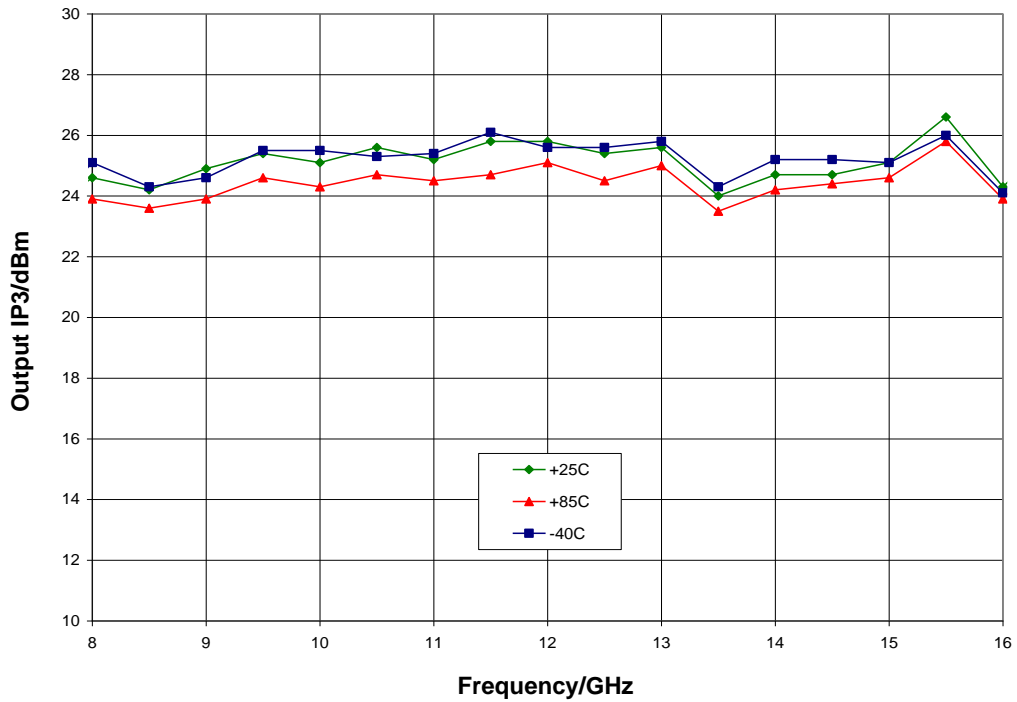


Psat vs.  $V_{dd}$ ,  $T_A = 25^\circ\text{C}$

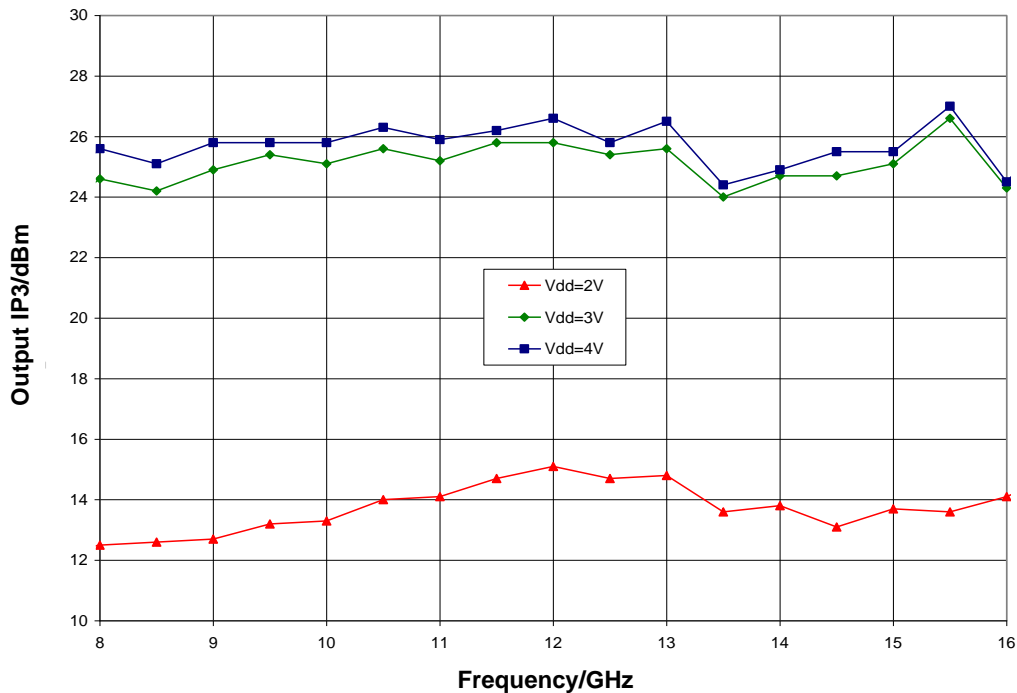


Typical Performance

Output IP3 vs. Temperature,  $V_{dd} = 3.0\text{ V}$



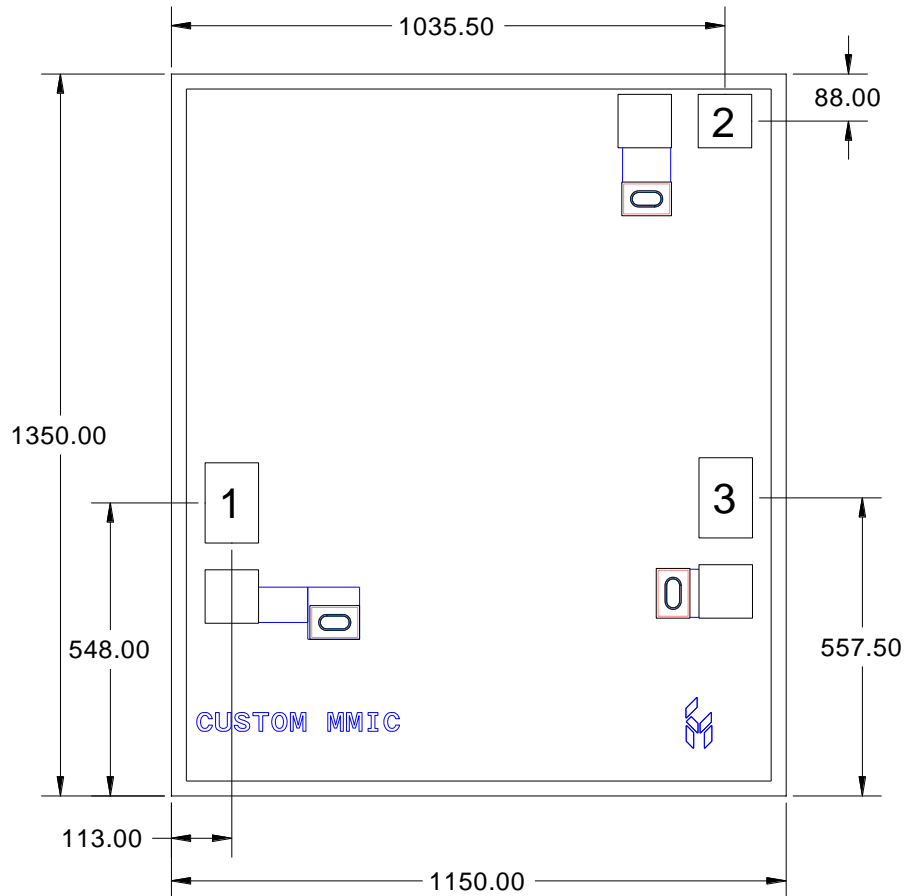
Output IP3 vs.  $V_{dd}$ ,  $T_A = 25^\circ\text{ C}$





Mechanical Information

Die Outline (all dimensions in microns)

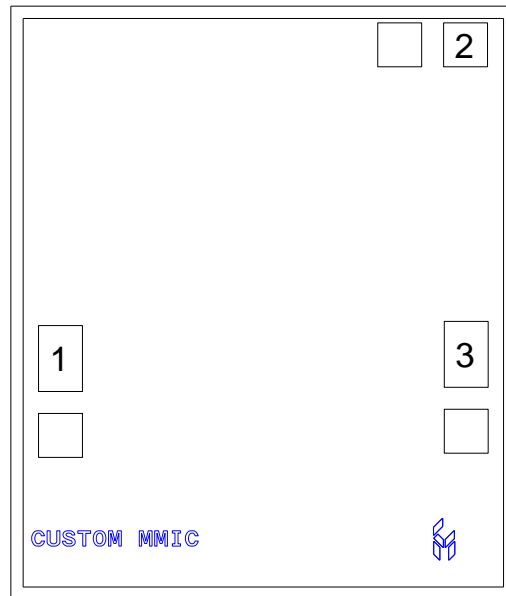


Notes:

1. No connection required for unlabeled pads
2. Backside is RF and DC ground
3. Backside and bond pad metal: Gold
4. Die is 100 microns thick
5. DC bond pad (2) is 100 microns square
6. RF bond pads (1, 3) are 100 x 150 microns

## Pad Description

### Pad Diagram



### Functional Description

Pad	Function	Description	Schematic
1	RF in	DC blocked and 50 ohm matched	
2	V <sub>dd</sub>	Power supply voltage Decoupling and bypass caps required	
3	RF out	DC blocked and 50 ohm matched	
Backside	Ground	Connect to RF / DC ground	

**Applications Information**

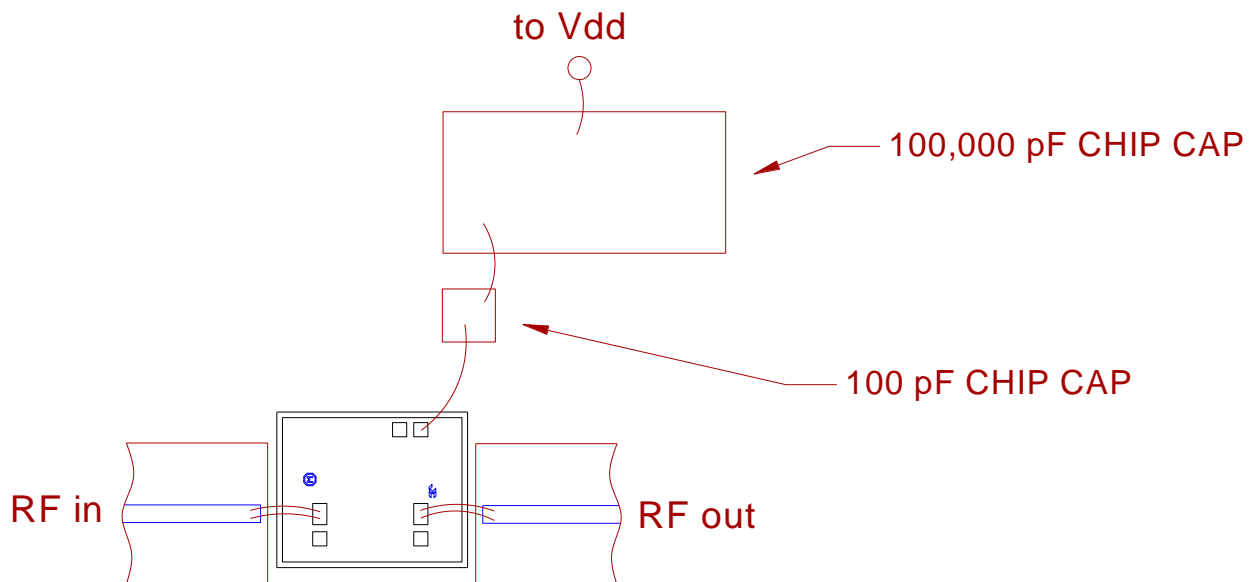
**Assembly Guidelines**

The backside of the CMD307 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a double bond wire as shown.

The semiconductor is 100 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

**Assembly Diagram**



**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

## Applications Information

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### Biasing and Operation

The CMD307 is biased with a positive drain supply. Performance is optimized when the drain voltage is set to +3.0 V, though it may be set to a minimum of +2.0 V and a maximum of +4.0 V.

Turn ON procedure:

1. Apply drain voltage  $V_{dd}$  and set to +3 V

Turn OFF procedure:

1. Turn off drain voltage  $V_{dd}$

RF power can be applied at any time.

## Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1A	ESDA / JEDEC JS-001-2012



Caution!  
ESD-Sensitive Device

## RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- SVHC Free
- PFOS Free
- Halogen Free



## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

**Web:** [www.qorvo.com](http://www.qorvo.com)

**Tel:** 1-844-890-8163

**Email:** [customer.support@qorvo.com](mailto:customer.support@qorvo.com)

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